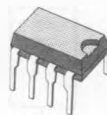


CMOS DUAL OPERATIONAL AMPLIFIERS

- EXCELLENT PHASE MARGIN ON CAPACITANCE LOADS
- SYMMETRICAL OUTPUT CURRENTS
- HIGH GAIN BANDWIDTH PRODUCT FOR TS272
- LOW OUTPUT DYNAMIC IMPEDANCE
- THE TRANSFER FUNCTION IS LINEAR
- PIN COMPATIBLE TO STANDARD DUAL OPERATIONAL AMPLIFIERS (TL082 - LM358)
- STABLE AND LOW OFFSET VOLTAGE
- INTERNAL ELECTROSTATIC DISCHARGE (ESD) PROTECTION CIRCUITS
- THREE INPUT OFFSET VOLTAGE SELECTIONS : STANDARD (10 mV), A (5 mV), B (2 mV)



N
DIP8
(Plastic package)

J
CERDIP8
(Cerdip package)



D
SO8
(Plastic micropackage)

(Ordering Information at the end of the datasheet)

DESCRIPTION

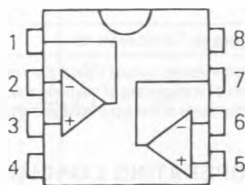
The TS272 series are low cost, low power dual operational amplifiers designed to operate with single or dual supplies. These operational amplifiers use the SGS THOMSON Microelectronics silicon gate LIN MOS process giving them an excellent consumption speed ratio. These series are ideally suited for low consumption applications.

Three power consumptions are available allowing to have always the best consumption-speed ratio.

- $I_{CC} = 10 \mu A$ per amplifier : TS27L2 (Low bias versions)
- $I_{CC} = 150 \mu A$ per amplifier : TS27M2 (Medium bias versions)
- $I_{CC} = 1 mA$ per amplifier : TS272 (High bias versions)

The input impedance is similar to the J-FET input impedance. Very high input impedance and extremely low input offset and bias currents. They allow to minimize the static errors in low impedance applications.

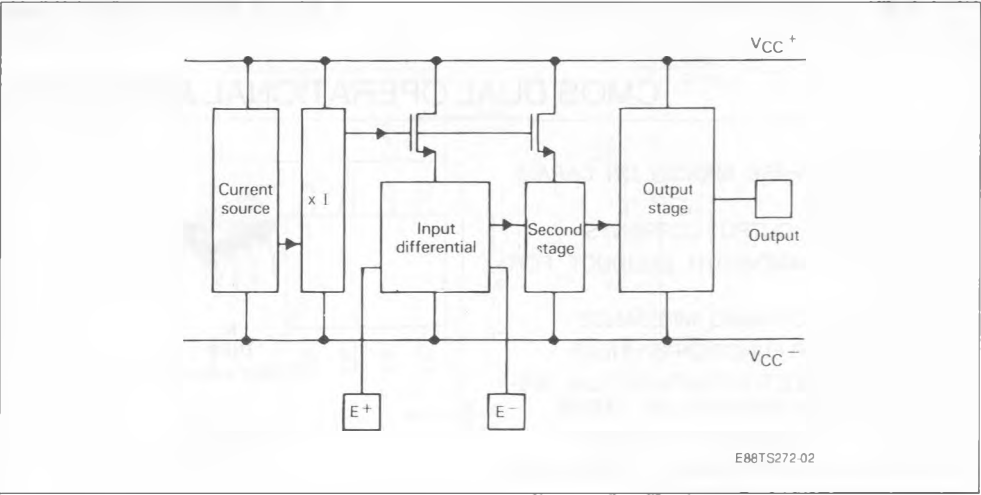
PIN CONNECTIONS (top view)



E88TS272-01

- 1 - Output 1
- 2 - Inverting input 1
- 3 - Non-inverting input 1
- 4 - V_{CC}^-
- 5 - Non-inverting input 2
- 6 - Inverting input 2
- 7 - Output 2
- 8 - V_{CC}^+

BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS

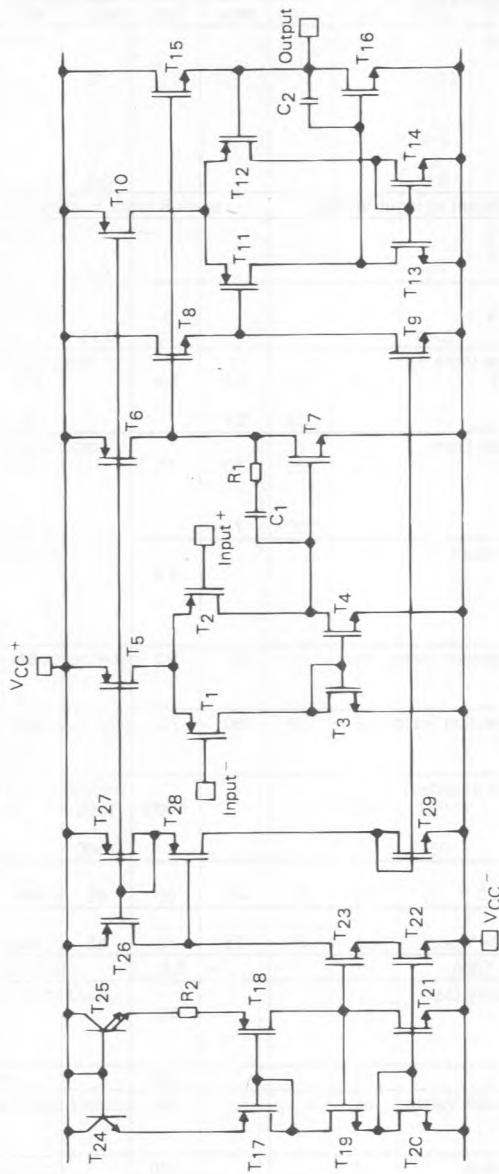
Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage (note 1)	12	V
V_{id}	Differential Input Voltage (note 2)	± 12	V
V_i	Input Voltage (note 3)	- 0.3 to 12	V
T_{oper}	Operating Free-air Temperature		
	TS272C	0 to 70	°C
	TS272I	- 40 to 105	
	TS272M	- 55 to 125	
	TS27M2C	0 to 70	
	TS27M2I	- 40 to 105	
	TS27M2M	- 55 to 125	
	TS27L2C	0 to 70	
	TS27L2I	- 40 to 105	
	TS27L2M	- 55 to 125	
T_{sig}	Storage Temperature	- 65 to 150	°C

Notes : 1. All voltage values, except differential voltages, are with respect to network ground terminal.
2. Differential voltages are at the non-inverting input terminal respect to the terminal.
3. The magnitude of the input voltage must never exceed the magnitude of the positive supply voltage.

OPTIMAL OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage (note 1)	4 to 10	V
V_i	Common Mode Input Voltage $V_{CC} = 10$ V	0 to 9	V

SCHEMATIC DIAGRAM (For 1/2 TS27x2)



E88TS272-03

ELECTRICAL CHARACTERISTICS FOR TS272
 $T_{amb} = 25^{\circ}\text{C}$, $V_{CC} = 10\text{ V}$ (unless otherwise specified)

 R_L Connected to V_{CC} —

Symbol	Parameter	TS272C			TS272I/TS272M			Unit
		Min.	Typ.	Max.	Min.	Typ.	Max.	
V_{io}	Input Offset Voltage $V_o = 1.4\text{ V}$ TS272 $T_{min} < T < T_{max}$ TS272A $T_{min} < T < T_{max}$ TS272B $T_{min} < T < T_{max}$			10 12 5 6.5 2 3.5			10 12 5 6.5 2 3.5	mV
αV_{io}	Temperature Coefficient of Input Voltage		5			5		$\mu\text{V}/^{\circ}\text{C}$
I_{io}	Input Offset Current $V_i = 5\text{ V}$, $V_o = 5\text{ V}$ $T_{min} < T < T_{max}$		1	0.1		1	0.2	pA nA
I_{IB}	Input Bias Current $V_i = 5\text{ V}$, $V_o = 5\text{ V}$ $T_{min} < T < T_{max}$		1	0.15		1	0.3	pA nA
V_{OH}	High Output Voltage (note 1) $V_i = 10\text{ mV}$ $R_L = 10\text{ k}\Omega$ $T_{min} < T < T_{max}$	8.2 8.1	8.4		8.2 8	8.4		V
A_{vd}	Large Signal Voltage Gain $V_o = 1\text{ V to } 6\text{ V}$ $V_i = 5\text{ V}$ $R_L = 10\text{ k}\Omega$ $T_{min} < T < T_{max}$	10 7	15		10 6	15		V/mV
G_{wr}	Gain Bandwidth Product $A_v = 40\text{ dB}$ $R_L = 10\text{ k}\Omega$ $C_L = 100\text{ pF}$ $f_{in} = 200\text{ KHz}$		3.5			3.5		MHz
CMR	Common Mode Rejection Ratio $V_o = 1.4\text{ V}$ $V_i = 1\text{ V to } 7.4\text{ V}$	65	80		65	80		dB
SVR	Supply Voltage Rejection Ratio $V_{CC} = 5\text{ V to } 10\text{ V}$ $V_o = 1.4\text{ V}$	60	70		60	70		dB
I_{CC}	Supply Current (per amplifier) $A_v = 1$, no Load $V_o = 5\text{ V}$ $T_{min} < T < T_{max}$		1000	1500 1600		1000	1500 1700	μA
I_s	Output Current $V_i = 10\text{ mV}$, $V_o = 0\text{ V}$	45	60	85	45	60	85	mA
I_s (sink)	Output Current $V_i = -10\text{ mV}$, $V_o = V_{CC}$	35	45	65	35	45	65	mA
S_{VO}	Slew Rate at Unity Gain		5.5			5.5		V/ μS
ϕ_m	Phase Margin at Unity Gain $A_v = 40\text{ dB}$ $R_L = 10\text{ k}\Omega$ $C_L = 100\text{ pF}$		45			45		Degrees
K_{OV}	Overshoot Factor		30			30		%
V_n	Input Equivalent Noise Voltage $f = 1\text{ KHz}$ $R_s = 10\text{ }\Omega$		30			30		nV/ $\sqrt{\text{Hz}}$
V_{O1}/V_{O2}	Cross Talk Attenuation		120			120		dB

Note : 1. Low output voltage is less than 50mV.

ELECTRICAL CHARACTERISTICS FOR TS27M2 $T_{amb} = 25\text{ }^{\circ}\text{C}$, $V_{CC} = 10\text{ V}$ (unless otherwise specified) R_L Connected to V_{CC} —

Symbol	Parameter	TS27M2C			TS27M2I/TS27M2M			Unit
		Min.	Typ.	Max.	Min.	Typ.	Max.	
V_{io}	Input Offset Voltage $V_o = 1.4\text{ V}$ TS27M2 $T_{min} < T < T_{max}$ TS27M2A $T_{min} < T < T_{max}$ TS27M2B $T_{min} < T < T_{max}$			10 12 5 6.5 2 3.5			10 12 5 6.5 2 3.5	mV
αV_{io}	Temperature Coefficient of Input Voltage		2			2		$\mu\text{V}/^{\circ}\text{C}$
I_{io}	Input Offset Current $V_i = 5\text{ V}$, $V_o = 5\text{ V}$ $T_{min} < T < T_{max}$		1	0.1		1	0.2	pA nA
I_{IB}	Input Bias Current $V_i = 5\text{ V}$, $V_o = 5\text{ V}$ $T_{min} < T < T_{max}$		1	0.15		1	0.3	pA nA
V_{DH}	High Output Voltage (note 1) $V_i = 10\text{ mV}$ $R_L = 100\text{ k}\Omega$ $T_{min} < T < T_{max}$	8.7 8.6	8.9		8.7 8.5	8.9		V
A_{vd}	Large Signal Voltage Gain $V_o = 1\text{ V to }6\text{ V}$ $R_L = 100\text{ k}\Omega$ $V_i = 5\text{ V}$ $T_{min} < T < T_{max}$	30 20	50		30 10	50		V/mV
G_{wr}	Gain Bandwidth Product $A_v = 40\text{ dB}$ $R_L = 100\text{ k}\Omega$ $C_L = 100\text{ pF}$ $f_{in} = 100\text{ KHz}$		1			1		MHz
CMR	Common-mode Rejection Ratio $V_o = 1.4\text{ V}$ $V_i = 1\text{ V to }7.4\text{ V}$	65	80		65	80		dB
SVR	Supply Voltage Rejection Ratio $V_{CC} = 5\text{ V to }10\text{ V}$ $V_o = 1.4\text{ V}$	60	80		60	80		dB
I_{CC}	Supply Current (per amplifier) $A_v = 1$, no Load $V_o = 5\text{ V}$ $T_{min} < T < T_{max}$		150	200 250		150 200	200 300	μA
I_s	Output Current $V_i = 10\text{ mV}$, $V_o = 0\text{ V}$	45	60	85	45	60	85	mA
I_s (sink)	Output Current $V_i = -10\text{ mV}$, $V_o = V_{CC}$	35	45	65	35	45	65	mA
S_{Vo}	Slew Rate at Unity Gain		0.6			0.6		V/ μS
ϕ_m	Phase Margin at Unity Gain $A_v = 40\text{ dB}$ $R_L = 100\text{ k}\Omega$ $C_L = 100\text{ pF}$		45			45		Degrees
K_{OV}	Overshoot Factor		30			30		%
V_n	Input Equivalent Noise Voltage $f = 1\text{ KHz}$ $R_S = 10\text{ }\Omega$		38			38		nV/ $\sqrt{\text{Hz}}$
V_{O1}/V_{O2}	Cross Talk Attenuation		120			120		dB

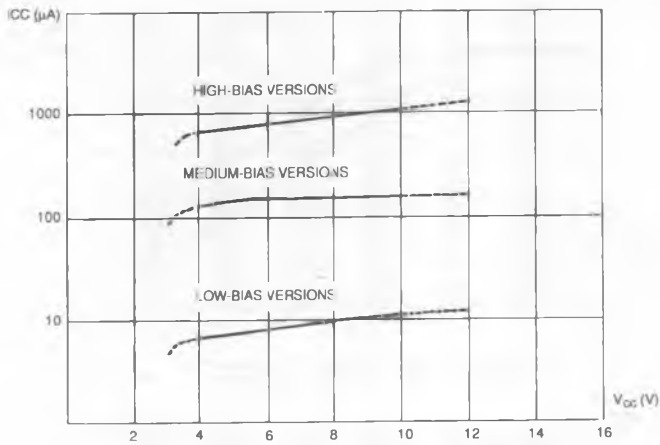
Note : 1. Low output voltage is less than 50mV.

ELECTRICAL CHARACTERISTICS FOR TS27L2
 $T_{amb} = 25^{\circ}\text{C}$, $V_{CC} = 10\text{ V}$ (unless otherwise specified)

 R_L Connected to V_{CC}

Symbol	Parameter	TS27L2C			TS27L2I/TS27L2M			Unit
		Min.	Typ.	Max.	Min.	Typ.	Max.	
V_{IO}	Input Offset Voltage $V_o = 1.4\text{ V}$ TS27L2 $T_{min} < T < T_{max}$ TS27L2A $T_{min} < T < T_{max}$ TS27L2B $T_{min} < T < T_{max}$			10 12 5 6.5 2 3.5			10 12 5 6.5 2 3.5	mV
αV_{IO}	Temperature Coefficient of Input Voltage		0.7			0.7		$\mu\text{V}/^{\circ}\text{C}$
I_{IO}	Input Offset Current $V_i = 5\text{ V}$, $V_o = 5\text{ V}$ $T_{min} < T < T_{max}$		1	0.1		1	0.2	pA nA
I_{IB}	Input Bias Current $V_i = 5\text{ V}$, $V_o = 5\text{ V}$ $T_{min} < T < T_{max}$		1	0.15		1	0.3	pA nA
V_{DH}	High Output Voltage (note 1) $V_i = 10\text{ mV}$ $R_L = 1\text{ M}\Omega$ $T_{min} < T < T_{max}$	8.8 8.7	9		8.8 8.6	9		V
A_{vd}	Large Signal Voltage Gain $V_o = 1\text{ V to } 6\text{ V}$ $R_L = 1\text{ M}\Omega$ $V_i = 5\text{ V}$ $T_{min} < T < T_{max}$	60 45	100		60 40	100		V/mV
G_{wr}	Gain Bandwidth Product $A_v = 40\text{ dB}$ $R_L = 1\text{ M}\Omega$ $C_L = 100\text{ pF}$ $F_{in} = 100\text{ KHz}$		0.1			0.1		MHz
CMR	Common Mode Rejection Ratio $V_o = 1.4\text{ V}$ $V_i = 1\text{ V to } 7.4\text{ V}$	65	80		65	80		dB
SVR	Supply Voltage Rejection Ratio $V_{CC} = 5\text{ V to } 10\text{ V}$ $V_o = 1.4\text{ V}$	60	80		60	80		dB
I_{CC}	Supply Current (per amplifier) $A_v = 1$, no Load $V_o = 5\text{ V}$ $T_{min} < T < T_{max}$		10	15 17		10	15 18	μA
I_s	Output Current $V_i = 10\text{ mV}$, $V_o = 0\text{ V}$	45	60	85	45	60	85	mA
I_s (Sink)	Output Current $V_i = -10\text{ mV}$, $V_o = V_{CC}$	35	45	65	35	45	65	mA
S_{VO}	Slew Rate at Unity Gain		0.04			0.04		V/ μS
ϕ_m	Phase Margin at Unity Gain $A_v = 40\text{ dB}$ $R_L = 1\text{ M}\Omega$ $C_L = 100\text{ pF}$		45			45		Degrees
K_{OV}	Overshoot Factor		30			30		%
V_n	Input Equivalent Noise Voltage $f = 1\text{ KHz}$ $R_S = 10\text{ }\Omega$		70			70		nV/ $\sqrt{\text{Hz}}$
V_{O1}/V_{O2}	Cross Talk Attenuation		120			120		dB

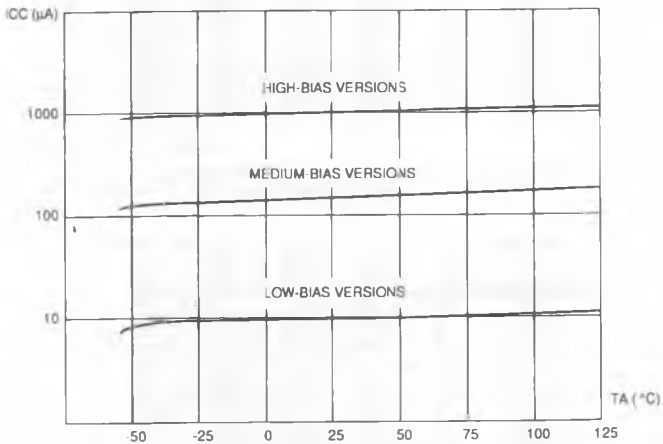
Note : 1. Low output voltage is less than 50mV.



SUPPLY CURRENT vs FREE-AIR TEMPERATURE

 $V_O = V_{IC} = 0.2 V_{CC}$, $T_{amb} = 25^\circ C$, NO LOAD

E88TS272-04

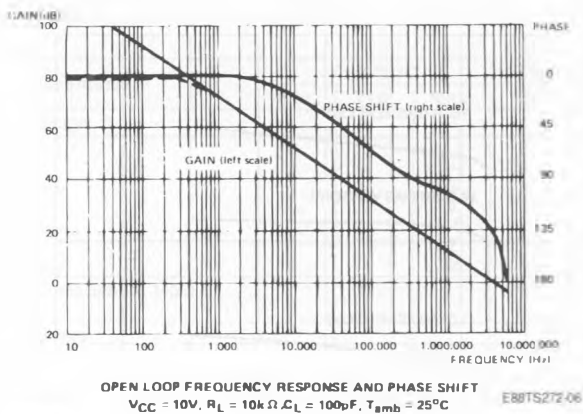


SUPPLY CURRENT vs FREE-AIR TEMPERATURE

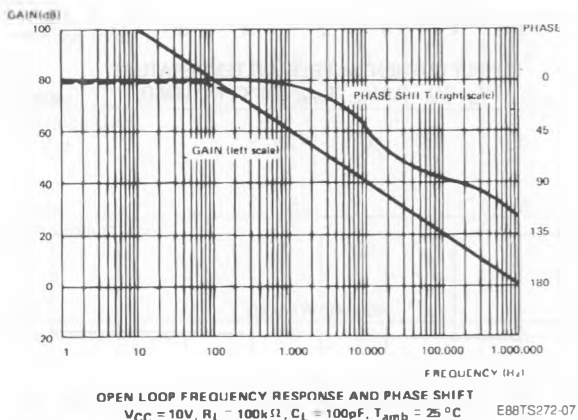
 $V_{CC} = 10 V$, $V_{IC} = 5 V$, $V_O = 5 V$, NO LOAD

E88TS272-05

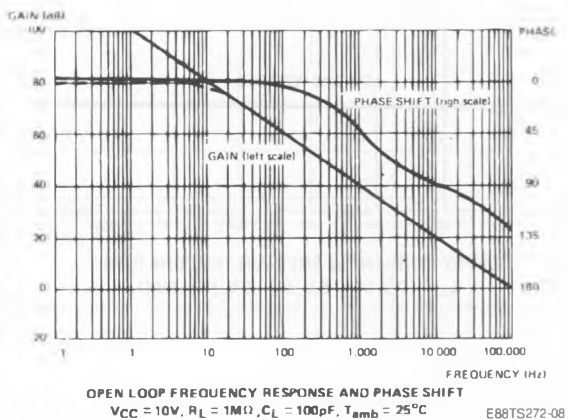
TS272



TS27M2



TS27L2

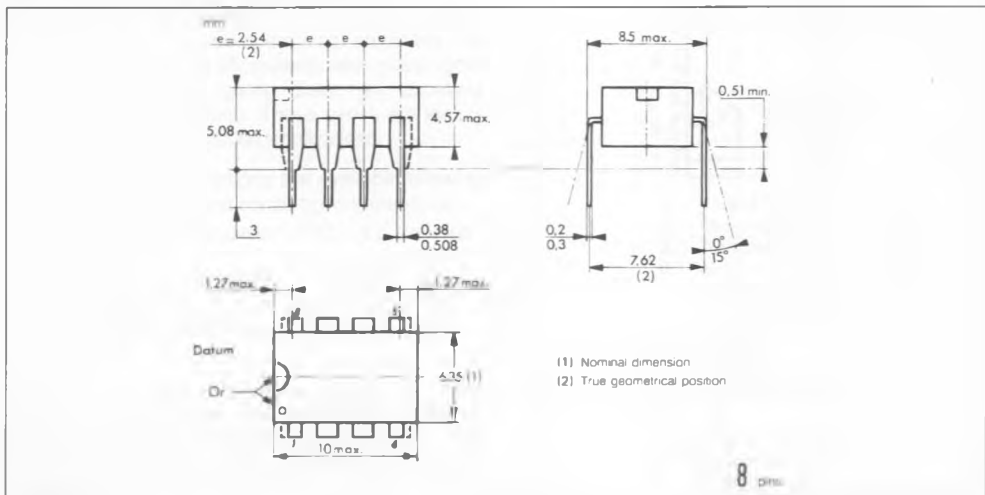


ORDERING INFORMATION

Part Number	Temperature Range °C	Package		
		N	D	J
TS272C	0 to 70	•	•	
TS272AC	0 to 70	•	•	
TS272BC	0 to 70	•	•	
TS272I	-40 to 105	•	•	
TS272M	-55 to 125			•
TS27M2C	0 to 70	•	•	
TS27M2AC	0 to 70	•	•	
TS27M2BC	0 to 70	•	•	
TS27M2I	-40 to 105	•	•	
TS27M2M	-55 to 125			•
TS27L2C	0 to 70	•	•	
TS27L2AC	0 to 70	•	•	
TS27L2BC	0 to 70	•	•	
TS27M2I	-40 to 105	•	•	
TS27L2M	-55 to 125			•
TS272AI	-40 to 105	•	•	
TS272BI	-40 to 105	•	•	
TS272AM	-55 to 125			•
TS272BM	-55 to 125			•
TS27M2AI	-40 to 105	•	•	
TS27M2BI	-40 to 105	•	•	
TS27L2AI	-40 to 105	•	•	
TS27L2BI	-40 to 105	•	•	
TS27M2AM	-55 to 125			•
TS27M2BM	-55 to 125			•
TS27L2AM	-55 to 125			•
TS27L2BM	-55 to 125			•
Examples : TS27L2ACN, TS272CD				

PACKAGE MECHANICAL DATA

8 PINS - PLASTIC DIP OR Cerdip



PACKAGE MECHANICAL DATA (continued)

8 PINS - PLASTIC MICROPACKAGE SO

